



SI4910DY-T1-GE3 Information



For Reference Only

Part Number SI4910DY-T1-GE3 **Manufacturer** Vishay Siliconix

Category Discrete Semiconductor Products

Transistors - FETs, MOSFETs - Arrays

DescriptionMOSFET 2N-CH 40V 7.6A 8-SOIC**Package**8-SOIC (0.154", 3.90mm Width)

For the pricing/inventory/lead time, please contact

us

Website: https://www.heisener.com E-mail: salesdept@heisener.com



Request a Quote

Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.









SI4910DY-T1-GE3 Specifications

	Report errors?
Supplier Device Package	8-SO
Package / Case	8-SOIC (0.154", 3.90mm Width)
Mounting Type	Surface Mount
Operating Temperature	-55°C ~ 150°C (TJ)
Power - Max	3.1W
Input Capacitance (Ciss) (Max) @ Vds	855pF @ 20V
Gate Charge (Qg) (Max) @ Vgs	32nC @ 10V
Vgs(th) (Max) @ Id	2V @ 250μA
Rds On (Max) @ Id, Vgs	27 mOhm @ 6A, 10V
Current - Continuous Drain (Id) @ 25°C	7.6A
Drain to Source Voltage (Vdss)	40V
FET Feature	Standard
FET Type	2 N-Channel (Dual)
Series	TrenchFET?
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SI4910DY-T1-GE3 Guarantees



Quality Guarantees

We provide 90 days warranty. *

If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



Service Guarantees

We guarantee 100% customer satisfaction.

Our experienced sales team and tech support team back our services to satisfy all our customers.

SI4910DY-T1-GE3 Payment Methods



















SI4910DY-T1-GE3 Shipping Methods













If you have any question about SI4910DY-T1-GE3, please do not hesitate to contact us!

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